INTEGRATED CIRCUITS

DATA SHEET

74ABT162244 74ABTH162244

16-bit buffer/line driver with 30Ω series termination resistors (3-State)

Product specification Supersedes data of 1998 Feb 25 IC23 Data Handbook





16-bit buffer/line driver with 30 Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

FEATURES

- 16-bit bus interface
- Multiple V_{CC} and GND pins minimize switching noise
- Power-up 3-State
- 3-State buffers
- Output capability: +12 mA/–32mA
- Live insertion/extraction permitted
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- Same part as 74ABT162244-1
- 74ABTH162244 incorporates bus hold data inputs which eliminate the need for external pull—up resistors to hold unused inputs
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs

DESCRIPTION

The 74ABT162244 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed.

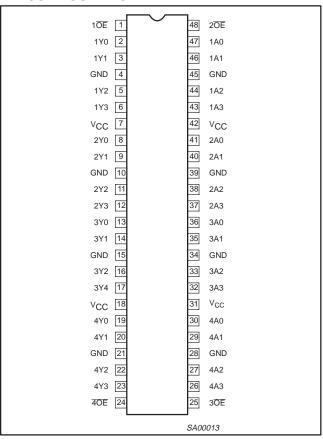
The 74ABT162244 device is a 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables ($1\overline{OE}$, $2\overline{OE}$, $3\overline{OE}$, $4\overline{OE}$), each controlling four of the 3-State outputs.

The 74ABT162244 is designed with 30Ω series resistance in both the upper and lower output structures. This design reduces line noise in applications such as memory address drivers, clock drivers and bus receivers/transmitters.

The 74ABT162244 is the same as the 74ABT16244-1. The part number has been changed to reflect industry standards.

Two options are available, 74ABT162244 which does not have the bus hold feature and the 74ABTH162244 which incorporates the bus hold feature.

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50pF; V_{CC} = 5V$	1.8 3.2	ns
C _{IN}	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	3	pF
C _{OUT}	Output capacitance	$V_O = 0V$ or V_{CC} ; 3-State	7	pF
I _{CCZ}	Quiescent supply current	Outputs disabled; V _{CC} = 5.5V	500	μΑ
I _{CCL}	Quiescent supply current	Outputs Low; V _{CC} = 5.5V	10	mA

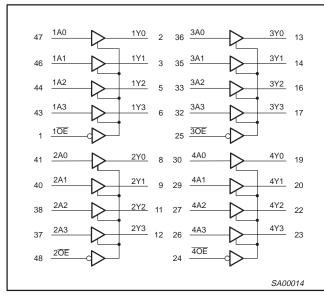
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ABT162244 DL	BT162244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABT162244 DGG	BT162244 DGG	SOT362-1
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ABTH162244 DL	BH162244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	−40°C to +85°C	74ABTH162244 DGG	BH162244 DGG	SOT362-1

16-bit buffer/line driver with 30Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

LOGIC SYMBOL



FUNCTION TABLE

INP	OUTPUTS	
nOE	nAx	nYx
L	L	L
L	Н	Н
Н	Х	Z

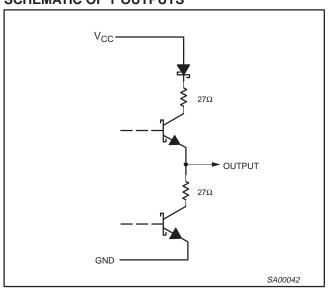
H = High voltage level

L = Low voltage level

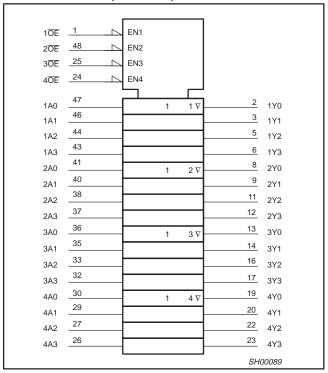
X = Don't care

Z = High impedance "off" state

SCHEMATIC OF Y OUTPUTS



LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 – 1A3, 2A0 – 2A3, 3A0 – 3A3, 4A0 – 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	10E, 20E, 30E, 40E	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

16-bit buffer/line driver with 30Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	-18	mA
V _I	DC input voltage ³		-1.2 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
,	DC output current	output in Low state	128	mA
Гоит	DC output current	output in High state	-64	IIIA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

RECOMMENDED OPERATING CONDITIONS

CVMDOL	DADAMETED	LIM		
SYMBOL	PARAMETER	Min	Max	UNIT
V _{CC}	DC supply voltage	4.5	5.5	V
V _I	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		12	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

^{3.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

16-bit buffer/line driver with 30Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

DC ELECTRICAL CHARACTERISTICS

					LIMITS				
SYMBOL PARAMETER		TEST CONDITIONS		T _{amb} = +25°C			T _{amb} = -40°C to +85°C		UNIT
				Min	Тур	Max	Min	Max	1
V _{IK}	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$			-0.9	-1.2		-1.2	V
		$V_{CC} = 4.5V; I_{OH} = -3mA; V_I = V_I$	L or V _{IH}	2.5	2.9		2.5		V
V_{OH}	High-level output voltage ³	$V_{CC} = 5V$; $I_{OH} = -3mA$; $V_I = V_{IL}$ or V_{IH}		3.0	3.4		3.0		V
		$V_{CC} = 4.5V; I_{OH} = -32mA; V_{I} = V_{OH}$	_{IL} or V _{IH}	2.0	2.4		2.0		V
\ /	l and land and and are	$V_{CC} = 4.5V; I_{OL} = 8mA; V_I = V_{IL}$	or V _{IH}			0.65		0.65	V
V_{OL}	Low-level output voltage	$V_{CC} = 4.5V; I_{OL} = 12mA; V_I = V_{II}$	or V _{IH}			0.80		0.80	V
I _I	Input leakage current	$V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$			±0.01	±1.0		±1.0	μΑ
	land lands are sured	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND	Control pins		±0.01	±1.0		±1.0	μΑ
II	Input leakage current 74ABTH162244	$V_{CC} = 5.5V; V_{I} = V_{CC}$	D		0.01	1.0		1.0	μΑ
		$V_{CC} = 5.5V; V_I = 0$	Data pins		-2.0	-3.0		-5.0	μΑ
		$V_{CC} = 4.5V; V_{I} = 0.8V$		50			50		
I _{HOLD}	Bus Hold Current A Inputs ⁴ 74ABTH162244	V _{CC} = 5.5V; V _I = 2.0V		-75			-75		μΑ
		$V_{CC} = 5.5V; V_I = 0 \text{ to } 5.5V$		±500					
I_{OFF}	Power-off leakage current	$V_{CC} = 0.0V; V_{O} \text{ or } V_{I} \le 4.5V$			±5.0	±100		±100	μΑ
I _{PU/PD}	Power-up/down 3-State output current	$V_{\underline{CC}}$ = 2.0V; $V_{\underline{O}}$ = 0.5V; $V_{\underline{I}}$ = GNI V $_{\underline{OE}}$ = Don't care	O or V _{CC} ;		±5.0	±50		±50	μА
I _{OZH}	3-State output High current	$V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = V_{IL}$	or V _{IH}		0.1	10		10	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 5.5V; V_{O} = 0.0V; V_{I} = V_{IL}$	or V _{IH}		-0.1	-10		-10	μΑ
I _{CEX}	Output High leakage current	$V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GNI$	O or V _{CC}		5.0	50		50	μΑ
Io	Output current ¹	$V_{CC} = 5.5V; V_{O} = 2.5V$		-50	-100	-180	-50	-180	mA
I _{CCH}		$V_{CC} = 5.5V$; Outputs High, $V_I = 0$	SND or V _{CC}		0.50	1.0		1.0	mA
I _{CCL}	Quiescent supply current ³	$V_{CC} = 5.5V$; Outputs Low, $V_I = G$	ND or V _{CC}		10	19		19	mA
I _{CCZ}		V_{CC} = 5.5V; Outputs 3-State; V_{I} = GND or V_{CC}			0.50	1.0		1.0	mA
		Outputs enabled, one data input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V			100	250		250	μΑ
ΔI_{CC}	Additional supply current per input pin ^{2, 3}	Outputs disabled, one data input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V			100	250		250	μΑ
		Control pins, outputs disabled, one enable input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V			100	250		250	μА

NOTES:

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- 2. This is the increase in supply current for each input at 3.4V.3. This data sheet limit may vary among suppliers.
- 4. This is the bus hold overdrive current required to force the input to the opposite logic state.

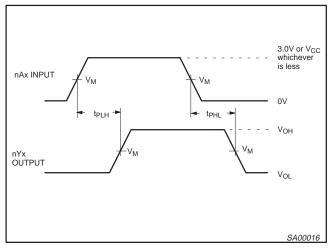
AC CHARACTERISTICS

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF, R_L = 500 Ω

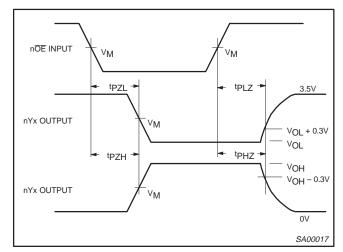
			LIMITS					
SYMBOL	PARAMETER	WAVEFORM		T _{amb} = +25°C V _{CC} = +5.0V		$T_{amb} = -40^{\circ}$ $V_{CC} = +5$	°C to +85°C .0V ±0.5V	UNIT
			Min	Тур	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1.0 1.6	1.8 3.2	2.4 4.0	1.0 1.6	2.7 4.4	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.2 2.6	2.7 5.0	3.5 6.2	1.2 2.6	4.3 7.3	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	1.5 1.3	3.0 2.6	3.8 3.3	1.5 1.3	4.5 4.6	ns

AC WAVEFORMS

 $V_M = 1.5V$, $V_{IN} = GND$ to 3.0V



Waveform 1. Input (An) to Output (Yn) Propagation Delays

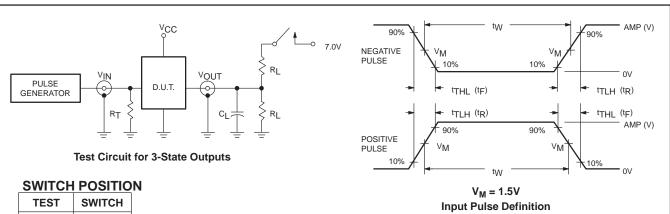


Waveform 2. 3-State Output Enable and Disable Times

16-bit buffer/line driver with 30Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PLZ}	closed
t _{PZL}	closed
All other	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS					
FAMILY	Amplitude	Rep. Rate	t _W	t _R	t _F	
74ABT/H16	3.0V	1MHz	500ns	2.5ns	2.5ns	

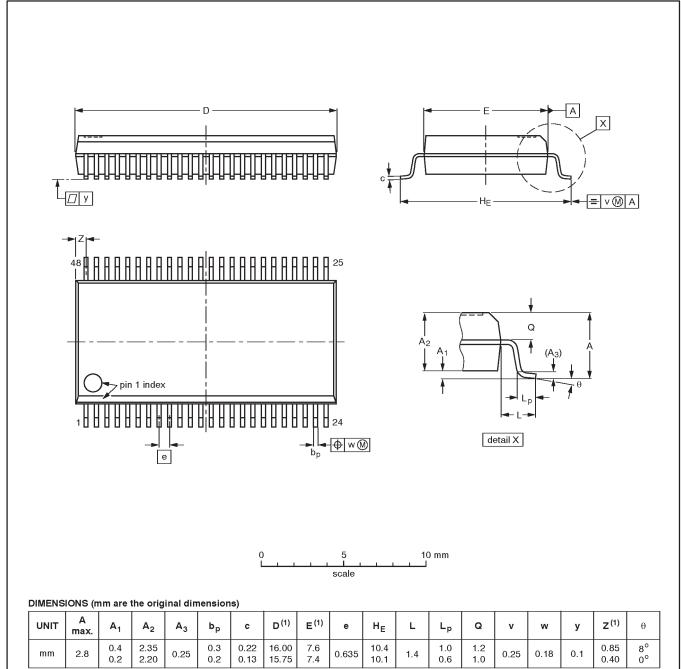
SA00018

16-bit buffer/line driver with 30Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



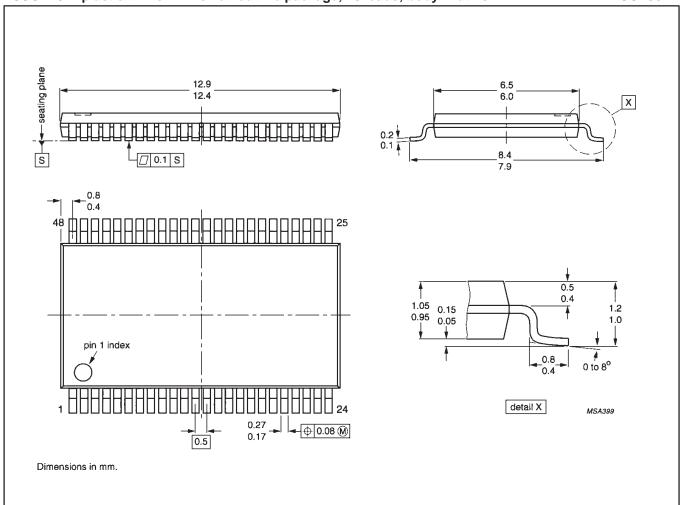
Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE	E REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT370-1		MO-118AA				93-11-02 95-02-04

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



16-bit buffer/line driver with 30Ω series termination resistors (3-State)

74ABT162244 74ABTH162244

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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print code Date of release: 05-96

Document order number: 9397-750-04708

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